

# PHOTO COUPLERS

## PS2403-1, PS2403-2, PS2403-3, PS2403-4

### MULTI PHOTO COUPLER HIGH ISOLATION VOLTAGE SINGLE TRANSISTOR TYPE

#### DESCRIPTION

The PS2403-1, -2, -3 and -4 series are optically coupled isolator containing a GaAs light emitting diode and an NPN silicon photo transistor. Each is mounted in a dual in-line package.

#### FEATURES

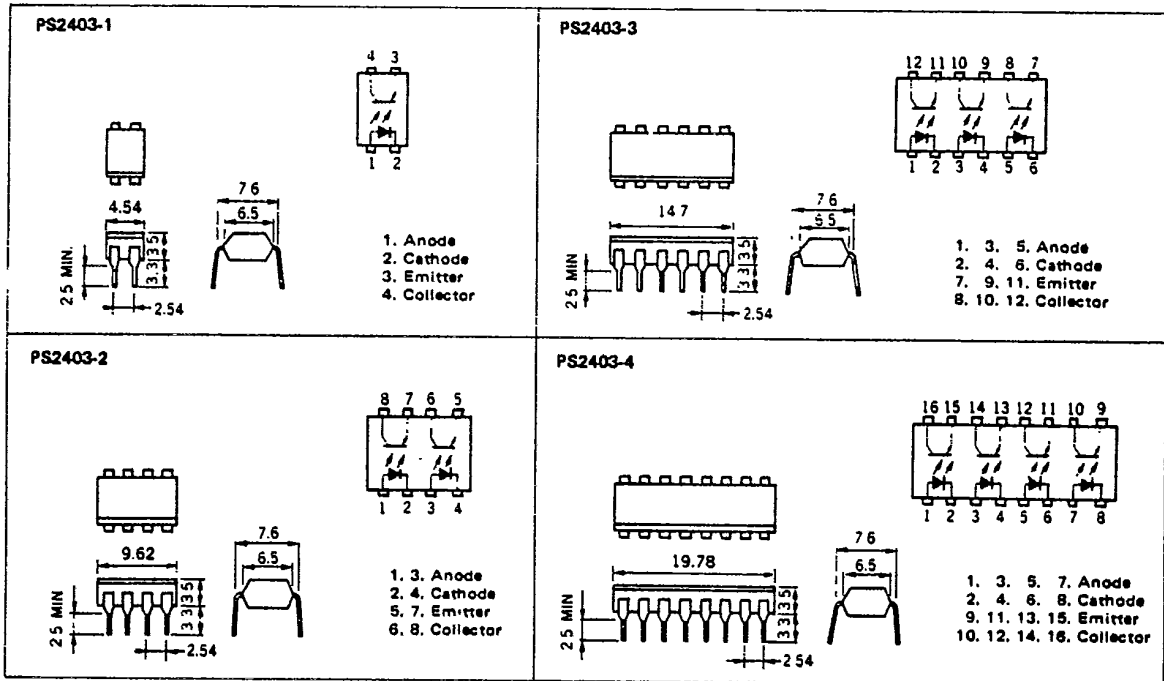
- Small package size
- Each isolated channels per package
- High isolation voltage 5 000 V<sub>ac</sub> Rating
- Low input current
- Low cost
- UL recognized

#### APPLICATIONS

Interface circuit for various instrumentations, control equipments.

- AC Line/Digital Logic . . . . . Isolate high voltage transients
- Digital Logic/Digital Logic . . . . . Eliminate spurious ground loops
- Twisted pair line receiver . . . . . Eliminate ground loop pick-up
- Telephone/Telegraph line receiver . . . . . Isolate high voltage transients
- High Frequency Power Supply  
Feedback Control . . . . . Maintain floating ground
- Relay contact monitor . . . . . Isolate floating grounds and transients
- Power Supply Monitor . . . . . Isolate transients and ground systems

#### PACKAGE DIMENSIONS (Unit : mm)



**PS2403-1, PS2403-2, PS2403-3, PS2403-4**

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**ABSOLUTE MAXIMUM RATINGS ( $T_a = 25^\circ\text{C}$ )**

Diode		(PS2403-1)	(PS2403-2, PS2403-3, PS2403-4)	
Reverse Voltage	$V_R$	6.0	6.0	V
Forward Current (DC)	$I_F$	50	50	mA
Power Dissipation	$P_D$	150	120	mW/Unit
Peak Forward Current (300 $\mu\text{s}$ , 2 % duty cycle)	$I_{F(\text{peak})}$	3	3	A
<b>Transistor</b>				
Collector to Emitter Voltage	$V_{CEO}$	40	40	V
Emitter to Collector Voltage	$V_{ECO}$	7	7	V
Collector Current	$I_C$	30	30	mA
Power Dissipation	$P_C$	150	120	mW/Unit
Isolation Voltage *1	BV	5000	5000	$V_{ac}$
Storage Temperature	$T_{stg}$	-55 to +150	-55 to +150	$^\circ\text{C}$
Operating Temperature	$T_{opt}$	-55 to +100	-55 to +100	$^\circ\text{C}$
Lead Temperature (Soldering 10 s)	$T_{sol}$	260	260	$^\circ\text{C}$
Total Power Dissipation	$P_T$	250	200	mW/Unit

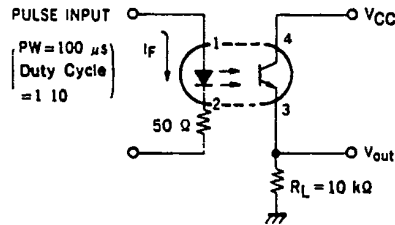
**ELECTRICAL CHARACTERISTICS ( $T_a = 25^\circ\text{C}$ )**

	CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Diode	Forward Voltage	$V_F$		1.1	1.3	V	$I_F = 1 \text{ mA}$
	Reverse Current	$I_R$			5	$\mu\text{A}$	$V_R = 5 \text{ V}$
	Junction Capacitance	C		50		pF	$V = 0, f = 1.0 \text{ MHz}$
Transistor	Collector to Emitter Dark Current	$I_{CEO}$			100	nA	$V_{CE} = 40 \text{ V}, I_F = 0$
	Collector to Emitter Breakdown Voltage	$BV_{CEO}$	40	60		V	$I_C = 1 \text{ mA}, I_B = 0$
	Emitter to Collector Breakdown Voltage	$BV_{ECO}$	7	9		V	$I_E = 100 \mu\text{A}, I_B = 0$
Coupled	Current Transfer Ratio *2	$CTR(I_C/I_F)$	100	200	400	%	$I_F = 1 \text{ mA}, V_{CE} = 5.0 \text{ V}$
	Collector Saturation Voltage	$V_{CE(sat)}$			0.25	V	$I_F = 1 \text{ mA}, I_C = 0.2 \text{ mA}$
	Isolation Resistance	$R_{1-2}$	$10^{11}$			$\Omega$	$V_{in-out} = 1.0 \text{ kV}$
	Isolation Capacitance	$C_{1-2}$		0.5		pF	$V = 0, f = 1.0 \text{ MHz}$
	Rise Time *3	$t_r$		8		$\mu\text{s}$	$V_{CC} = 5 \text{ V}, I_F = 1 \text{ mA}, R_L = 10 \text{ k}\Omega$
Fall Time *3	$t_f$		60		$\mu\text{s}$	$V_{CC} = 5 \text{ V}, I_F = 1 \text{ mA}, R_L = 10 \text{ k}\Omega$	

\*1 AC voltage for 1 minute at  $T_a = 25^\circ\text{C}$   
RH = 60 %

\*2 CTR rank (Only PS2403-1)  
KY: 200 % to 400 %  
LY: 150 % to 300 %  
MY: 100 % to 200 %

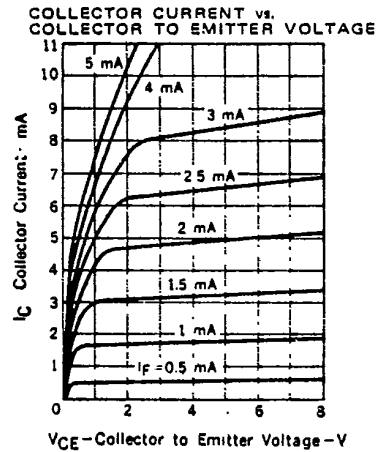
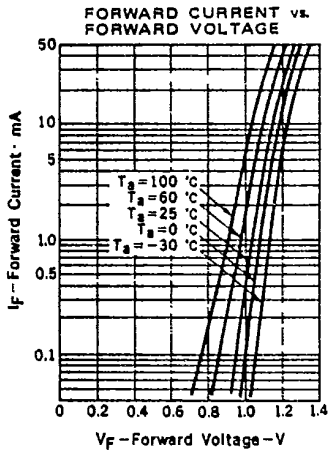
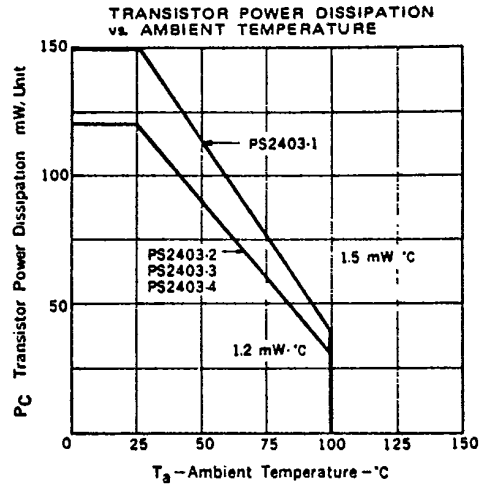
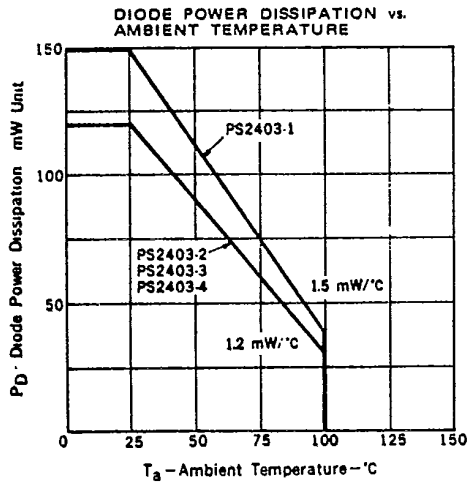
\*3 Test Circuit for Switching Time



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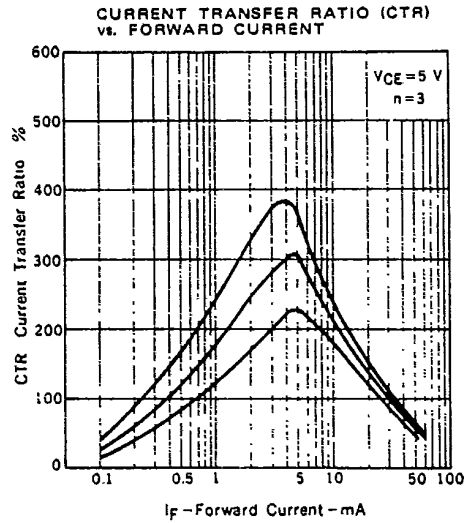
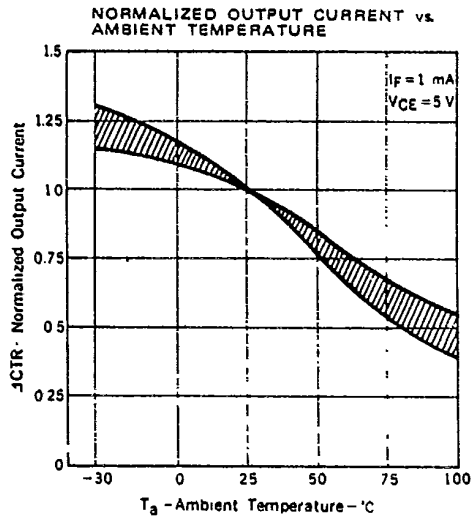
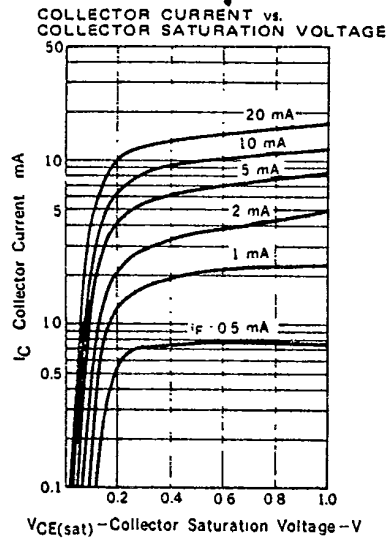
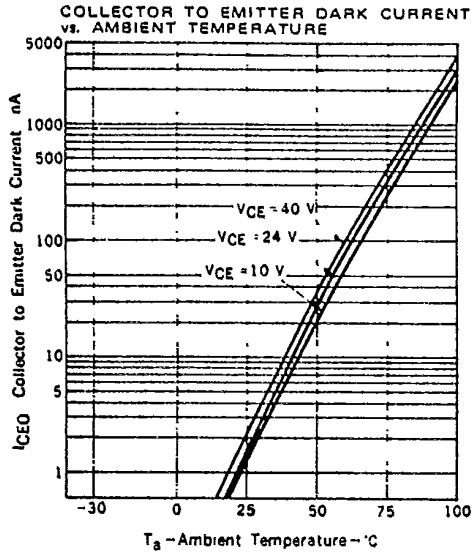
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TYPICAL CHARACTERISTICS ( $T_a = 25^\circ\text{C}$ )



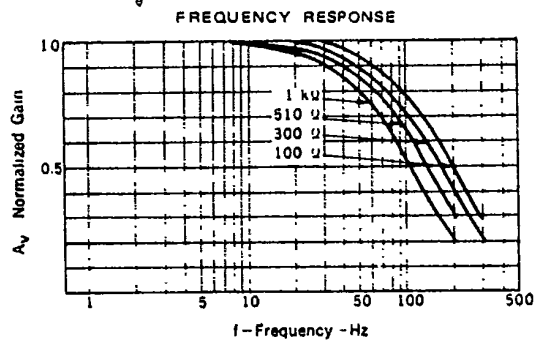
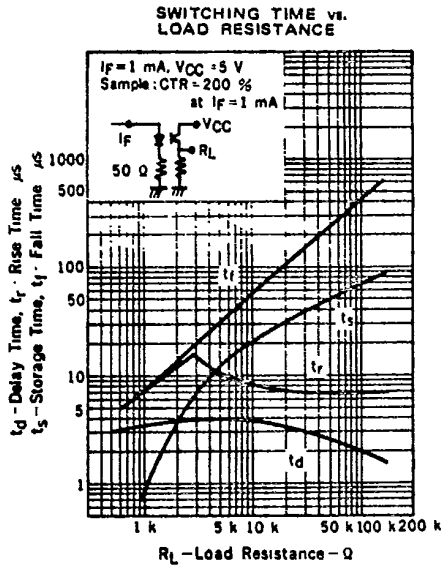
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